#### **General Description**

The MAX4645/MAX4646 single-pole, single-throw (SPST) analog switches feature a  $2.5\Omega$  typical on-resistance (RoN) from a +5V supply. RoN is flat (0.4 $\Omega$  max) over the specified signal range. Each switch can handle Rail-to-Rail® analog signals. Off-leakage current is 0.25nA max at +25°C. These analog switches are ideal in low-distortion applications and are the preferred solution over mechanical relays in automated test equipment or applications where current switching is required. They have low power requirements, require less board space, and are more reliable than mechanical relays.

These switches operate from a +1.8V to +5V single supply, making them ideal for use in battery-powered applications. The MAX4645/MAX4646 have fast switching speeds of 12ns turn-on time (t<sub>ON</sub>) and 8ns turn-off time (t<sub>OFF</sub>).

The MAX4645 is a normally open (NO) switch, and the MAX4646 is a normally closed (NC) switch. Both are available in 5-pin SOT23, 6-pin SOT23, and 8-pin  $\mu$ MAX packages.

#### Applications

- Battery-Powered Systems
- Audio and Video Signal Routing
- Low-Voltage Data-Acquisition Systems
- Sample-and-Hold Circuits
- Communications Circuits
- **Relay Replacement**

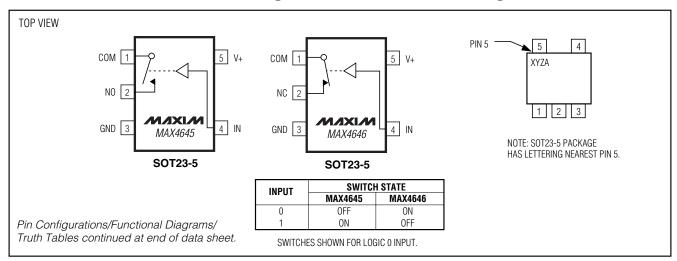
#### Features

- +1.8V to +5V Single-Supply Operation
- Guaranteed Ron
   2.5Ω max (5V supply)
   3.5Ω max (3V supply)
- 1.8V Operation RON 30Ω typ Over Temperature tON 40ns typ, tOFF 20ns typ
- Low Ron Flatness: 0.4Ω max
- Guaranteed Low Leakage Currents ±0.25nA at +25°C
- ♦ Rail-to-Rail Output Capability
- ◆ TTL/CMOS-Logic Compatible
- ♦ -75dB Off-Isolation at 1MHz
- Low Distortion: 0.014% typ

#### Ordering Information

PART	TEMP. RANGE	PIN- PACKAGE	TOP MARK
MAX4645EUT-T	-40°C to +85°C	5 SOT23-5	ADOB
MAX4645EUT-T	-40°C to +85°C	6 SOT23-6	AAHL
MAX4645EUA	-40°C to +85°C	8 µMAX	_
MAX4646EUK-T	-40°C to +85°C	5 SOT23-5	ADOC
MAX4646EUT-T	-40°C to +85°C	6 SOT23-6	AAHM
MAX4646EUA	-40°C to +85°C	8 µMAX	

Rail-to-Rail is a registered trademark of Nippon Motorola, Ltd.



#### Pin Configurations/Functional Diagrams/Truth Tables

#### 

\_ Maxim Integrated Products 1

*For free samples and the latest literature, visit www.maxim-ic.com or phone 1-800-998-8800. For small orders, phone 1-800-835-8769.* 

#### **ABSOLUTE MAXIMUM RATINGS**

V+, V <sub>IN</sub> to GND	0.3 to +6V
COM, NO, NC to GND (Note 1)	0.3V to (V+ + 0.3V)
Continuous Current (any terminal)	
Peak Current COM, NO, NC	
(pulsed at 1ms 10% duty cycle)	±100mA

Continuous Power Dissipation ( $T_A = +70^{\circ}C$ )
5-Pin SOT23 (derate 7.1mW/°C above+70°C)571mW
6-Pin SOT23 (derate 8.7mW/°C above +70°C)696mW
8-Pin µMAX (derate 4.1mW/°C above+70°C)
Operating Temperature Range40°C to +85°C
Storage Temperature Range65°C to +150°C
Lead Temperature (soldering, 10s)+300°C

Note 1: Signals on NO, NC, or COM, exceeding V+ or GND are clamped by internal diodes. Limit forward current to maximum current rating.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

#### ELECTRICAL CHARACTERISTICS—Single +5V Supply

 $(V_{+} = 4.5V \text{ to } 5.5V, V_{IH} = 2.4V, V_{IL} = 0.8V, T_{A} = T_{MIN} \text{ to } T_{MAX}$ , unless otherwise specified.) (Notes 2, 3)

PARAMETER	SYMBOL	CONDITI	MIN	ТҮР	MAX	UNITS		
ANALOG SWITCH							1	
Input Voltage Range	V <sub>COM</sub> , V <sub>NO</sub> , V <sub>NC</sub>			0		V+	V	
COM to NO or NC	Davi	$I_{COM} = 10 \text{mA},$	$T_A = +25^{\circ}C$		1.5	2.5	Ω	
On-Resistance	RON	$V_{NO}$ or $V_{NC} = 0$ to V+, V+ = 4.5V	$T_A = T_{MIN}$ to $T_{MAX}$			3		
On-Resistance Flatness	Deuterout	$I_{COM} = 10 \text{mA},$	$T_A = +25^{\circ}C$		0.1	0.4	Ω	
(Note 4)	R <sub>FLAT(ON)</sub>	$V_{NO}$ or $V_{NC} = 0$ to V+, V+ = 4.5V	$T_A = T_{MIN}$ to $T_{MAX}$			0.6		
Off-Leakage Current	I <sub>NO(OFF)</sub> ,	$V_{COM} = 1V, 4.5V;$ $V_{NO} \text{ or } V_{NC} = 4.5V, 1V;$	$T_A = +25^{\circ}C$	-0.25	0.01	0.25		
(NO or NC) (Notes 5, 6)	INC(OFF)	$V_{\rm NO}  Of  V_{\rm NC} = 4.5  V,  1  V,$ V+ = 5.5V	$T_A = T_{MIN}$ to $T_{MAX}$	-0.35		0.35	nA	
COM Off-Leakage Current		$V_{COM} = 1V, 4.5V;$ $V_{NO} \text{ or } V_{NC} = 4.5V, 1V;$	$T_A = +25^{\circ}C$	-0.25	0.01	0.25		
(Notes 5, 6)	ICOM(OFF)	F) $V_{NO} OF V_{NC} = 4.5V, TV, V_{+} = 5.5V$	$T_A = T_{MIN}$ to $T_{MAX}$	-0.35		0.35	- nA	
COM On-Leakage Current	laarvan	$V_{+} = 5.5V; V_{COM} = 4.5V,$ 1V; V <sub>NO</sub> or V <sub>NC</sub> = 4.5V,	$T_A = +25^{\circ}C$	-0.25	0.01	0.25	5 nA	
(Notes 5, 6)	ICOM(ON)	$1V$ , $V_{NO}$ of $V_{NC} = 4.5V$ , 1V, or floating	$T_A = T_{MIN}$ to $T_{MAX}$	-0.35		0.35		
LOGIC INPUT			•					
Input Logic High	VIH			2.4			V	
Input Logic Low	VIL					0.8	V	
Logic Input Current	lin	$V_{IN_{-}} = 0.8V \text{ or } 2.4V$		-0.1	0.005	0.1	μΑ	
SWITCH DYNAMIC CHARA	CTERISTICS							
Turn-On Time (Note 5)	ne (Note 5) t <sub>ON</sub> V <sub>NO</sub> , V <sub>NC</sub> = 3V, F		$T_A = +25^{\circ}C$		12	15	ns	
	CL :	$C_L = 35 pF$ , Figure 2	$T_A = T_{MIN}$ to $T_{MAX}$			18		
Turn-Off Time (Note 5)	toff	$V_{NO}$ , $V_{NC}$ = 3V, $R_L$ = 300 $\Omega$ ,	$\Omega$ , T <sub>A</sub> = +25°C		8	10	ns	
	OFF	$C_L = 35 pF$ , Figure 2	$T_A = T_{MIN}$ to $T_{MAX}$			12		



#### ELECTRICAL CHARACTERISTICS—Single +5V Supply (continued)

(V+ = 4.5V to 5.5V, V<sub>IH</sub> = 2.4V, V<sub>IL</sub> = 0.8V, T<sub>A</sub> = T<sub>MIN</sub> to T<sub>MAX</sub>, unless otherwise specified.) (Notes 2, 3)

PARAMETER	SYMBOL	CONDITIO	ONS	MIN TYP MAX	UNITS			
Charge Injection	Q			5	рС			
NO or NC Capacitance	C <sub>OFF</sub>	$V_{NO}$ , $V_{NC}$ = GND, f = 1MHz, Figure 5	$T_A = +25^{\circ}C$	17	pF			
COM Off-Capacitance	Ссом	V <sub>COM</sub> = GND, f = 1MHz, Figure 5	T <sub>A</sub> = +25°C	17	pF			
COM On-Capacitance	Ссом	$V_{COM} = V_{NO}, V_{NC} = GND$ f = 1MHz, Figure 5	T <sub>A</sub> = +25°C	38	pF			
Off-Isolation (Note 7)	Nucc		T <sub>A</sub> = +25°C	-55	dB			
On-isolation (Note 7)	V <sub>ISO</sub>	$\label{eq:VNO} \begin{split} V_{NO} &= V_{NC} = 1 V_{RMS}, \\ R_L &= 50 \Omega, \ C_L = 5 p F, \\ f &= 1 M Hz, \ Figure \ 4 \end{split}$	T <sub>A</sub> = +25°C	-75	dB			
Total Harmonic Distortion	THD	$ \begin{array}{l} R_{L} = 600\Omega,  5V_{P-P}, \\ f = 20Hz \text{ to } 20kHz \end{array} \qquad T_{A} = +25^\circC \\ \end{array} $		0.014	%			
POWER SUPPLY								
Positive Supply Current I I+ I		$V+ = 5.5V$ , $V_{IN} = 0$ or $V+$ , all channels on or off	$T_A = +25^{\circ}C$ $T_A = T_{MIN}$ to $T_{MAX}$	0.0001	μΑ			

#### ELECTRICAL CHARACTERISTICS—Single +3V Supply

 $(V + = 2.7V \text{ to } 3.3V, V_{IH} = 2.0V, V_{IL} = 0.4V, T_A = T_{MIN} \text{ to } T_{MAX}$ , unless otherwise specified.) (Notes 2, 3)

PARAMETER	SYMBOL	CONDITIC	MIN	ТҮР	MAX	UNITS		
ANALOG SWITCH				1			1	
Input Voltage Range	V <sub>COM</sub> , V <sub>NO</sub> , V <sub>NC</sub>			0		V+	V	
COM to NO or NC	Pou	$I_{COM} = 10 \text{mA},$ VNO or VNC = 0 to V+,	$T_A = +25^{\circ}C$		2.5	3.5	Ω	
On-Resistance	R <sub>ON</sub>	$V_{\rm NO}  01  V_{\rm NC} = 0.10  V_{\pm},$ V+ = 2.7V	$T_A = T_{MIN}$ to $T_{MAX}$			4.5	52	
On-Resistance Flatness		$I_{COM} = 10 \text{mA},$	$T_A = +25^{\circ}C$		0.5	0.9	θ Ω	
(Note 4)	Note 4) $ \begin{array}{c} R_{FLAT(ON)} \\ V_{NO} \text{ or } V_{NC} = 0 \text{ to } V_{+}, \\ V_{+} = 2.7V \end{array} $		$T_A = T_{MIN}$ to $T_{MAX}$			1	1 22	
Off-Leakage Current	I <sub>NO(OFF)</sub> ,	V <sub>COM</sub> = 1V, 3V; V <sub>NO</sub> or V <sub>NC</sub> = 3V, 1V;	$T_A = +25^{\circ}C$	-0.25	0.01	0.25	nA	
(NO or NC) (Notes 5, 6)	INC(OFF)	$V_{\rm NO}  01  V_{\rm NC} = 30,  10,  10,  100  {\rm V}_{\rm NC} = 3.3  {\rm V}_{\rm S}$	$T_A = T_{MIN}$ to $T_{MAX}$	-0.35		0.35		
COM Off-Leakage Current		V <sub>COM</sub> = 1V, 3V; V <sub>NO</sub> or V <sub>NC</sub> = 3V, 1V;	$T_A = +25^{\circ}C$	-0.25	0.01	0.25	nA	
(Notes 5, 6)	ICOM(OFF)	$V_{\rm HO} = 3.3V$	$T_A = T_{MIN}$ to $T_{MAX}$	-0.35		0.35		
COM On-Leakage Current	kade Current	$V_{+} = 3.3V; V_{COM} = 1V, 3V;$ V <sub>NO</sub> or V <sub>NC</sub> = 1V,	$T_A = +25^{\circ}C$	-0.25	0.01	0.25	nA	
(Notes 5, 6)	ICOM(ON)	3V or floating	$T_A = T_{MIN}$ to $T_{MAX}$	-0.35		0.35		

#### ELECTRICAL CHARACTERISTICS—Single +3V Supply (continued)

(V+ = 2.7V to 3.3V,  $V_{IH}$  = 2.0V,  $V_{IL}$  = 0.4V,  $T_A$  =  $T_{MIN}$  to  $T_{MAX}$ , unless otherwise specified.) (Notes 2, 3)

PARAMETER	SYMBOL	CONDITIO	MIN	ТҮР	MAX	UNITS	
LOGIC INPUT				1			
Input Logic High	VIH			2.0			V
Input Logic Low	VIL					0.4	V
Logic Input Current	lin	$V_{IN} = 0.4V \text{ or } 2.0V$		-1	0.005	1	μA
SWITCH DYNAMIC CHAR	ACTERISTICS						
		$V_{NO}$ , $V_{NC} = 2.0V$ ,	$T_A = +25^{\circ}C$		12	15	
Turn-On Time (Note 5)	ton	$R_L = 300\Omega$ , $C_L = 35pF$ , Figure 2	$T_A = T_{MIN}$ to $T_{MAX}$			20	ns
		$V_{NO}, V_{NC} = 2.0V,$	$T_A = +25^{\circ}C$		8	10	
Turn-Off Time (Note 5)	toff	$R_L = 300\Omega$ , $C_L = 35pF$ , Figure 2	$T_A = T_{MIN}$ to $T_{MAX}$			13	ns
Charge Injection	Q	$V_{GEN} = 1.5V, C_L = 1.0nF,$ $R_{GEN} = 0,$ Figure 3	T <sub>A</sub> = +25°C		4		рС
NO or NC Capacitance	COFF	V <sub>NO</sub> , V <sub>NC</sub> = GND, f = 1MHz, Figure 5	T <sub>A</sub> = +25°C		17		pF
COM Off-Capacitance	Ссом	V <sub>COM</sub> = GND, f = 1MHz, Figure 5	T <sub>A</sub> = +25°C		17		pF
COM On-Capacitance	Ссом	$V_{COM} = V_{NO}, V_{NC} = GND,$ f = 1MHz, Figure 5	T <sub>A</sub> = +25°C		38		pF
Off-Isolation (Note 7) $V_{ISO} = V_{NC} = 1V_{RMS},$ $F_{L} = 50\Omega, C_{L} = 5pF, f_{L} = 10MHz, Figure 4$ $V_{NO} = V_{NC} = 1V_{RMS},$		$R_L = 50\Omega$ , $C_L = 5pF$ ,	T <sub>A</sub> = +25°C	= +25°C -55			dB
		T <sub>A</sub> = +25°C		-75			
POWER SUPPLY							
Positive Supply Current	I+	$V$ + = 3.3V, $V_{IN}$ = 0 or V+,	$T_A = +25^{\circ}C$	0.0001			μA
r ositive Supply Current	1+	all channels on or off $T_A = T_{MIN}$ to $T_{MAX}$				1.0	

Note 2: The algebraic convention, where the most negative value is a minimum and the most positive value is a maximum, is used in this data sheet.

**Note 3:** SOT packages are 100% production tested at +25°C. Limits at the maximum rated temperature are guaranteed by correlation.

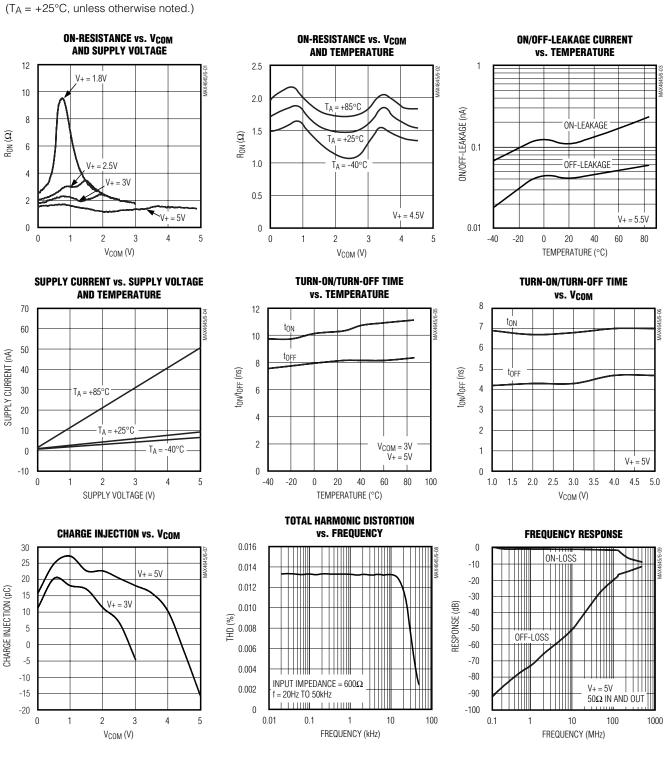
**Note 4:** Flatness is defined as the difference between the maximum and the minimum value of on-resistance as measured over the specified analog signal ranges.

Note 5: Guaranteed by design.

Note 6: Leakage parameters are 100% tested at +85°C and guaranteed by correlation at +25°C.

**Note 7:** Off-Isolation =  $20\log_{10}(V_{COM} / V_{NO})$ ,  $V_{COM}$  = output,  $V_{NO}$  = input to off switch.

#### **Typical Operating Characteristics**



M/IXI/M

MAX4645/MAX4646

5

#### Pin Description

		Р	IN				
	MAX4645			MAX4646			FUNCTION
SOT23-5	SOT23-6	μΜΑΧ	SOT23-5	SOT23-6	μΜΑΧ		
1	1	1	1	1	1	COM	Analog Switch Common Terminal
2	2	8	—	—	_	NO	Analog Switch Normally Open Terminal
	_		2	2	8	NC	Analog Switch Normally Closed Terminal
3	3	7	3	3	7	GND	Ground
4	4	6	4	4	6	IN	Logic Control Input
_	5	2, 3, 5	—	5	2, 3, 5	N.C.	No Connection. Not internally connected.
5	6	4	5	6	4	V+	Positive Supply Voltage

#### **Detailed Description**

The MAX4645/MAX4646 are low 2.5 $\Omega$  max on-resistance (at V+ = 5V), low-voltage analog switches that operate from a +1.8V to +5.5V single supply. CMOS switch construction allows processing analog signals that are within the supply voltage range (GND to V+).

#### **Applications Information**

Proper power-supply sequencing is recommended for all CMOS devices. Do not exceed the absolute maximum ratings because stresses beyond the listed ratings can cause permanent damage to the devices. Always sequence V+ on first, followed by the logic inputs, NO, or COM. If power-supply sequencing is not possible, add two small signal diodes (D1, D2) in series with the supply pins for overvoltage protection (Figure 1). Adding these diodes reduces the analog signal by one diode drop below V+ and one diode drop above GND, but does not affect the low switch resistance and low leakage characteristics of the device. Device operation is unchanged, and the difference between V+ and GND should not exceed 6V.

Although it is not required, power-supply bypassing improves noise margin and prevents switching noise from propagating from the V+ supply to other components. A  $0.1\mu$ F capacitor, connected from V+ to GND, is adequate for most applications.

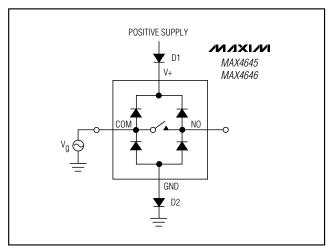


Figure 1. Overvoltage Protection Using Two External Blocking Diodes

#### **Test Circuits/Timing Diagrams**

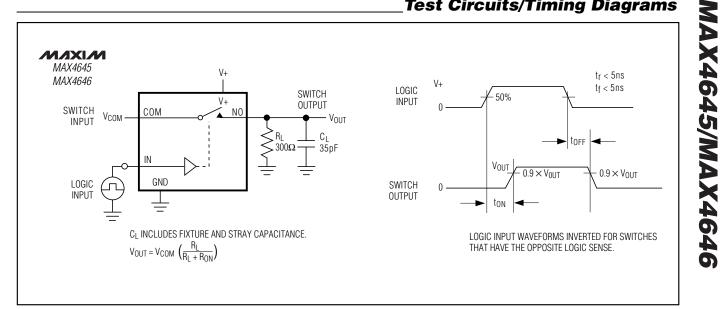


Figure 2. Switching Time

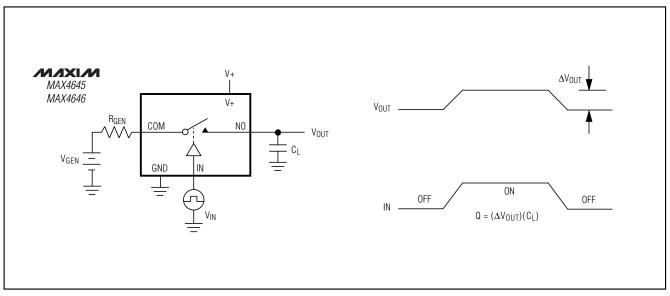
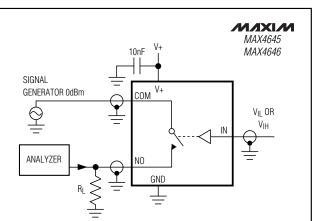


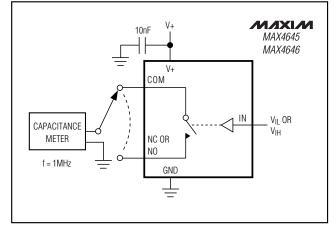
Figure 3. Charge Injection

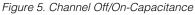
7

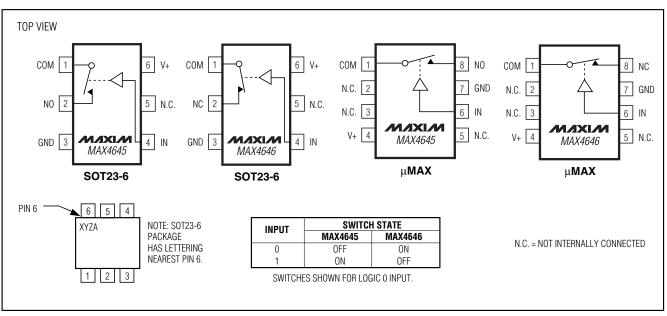




#### Test Circuits/Timing Diagrams (continued)







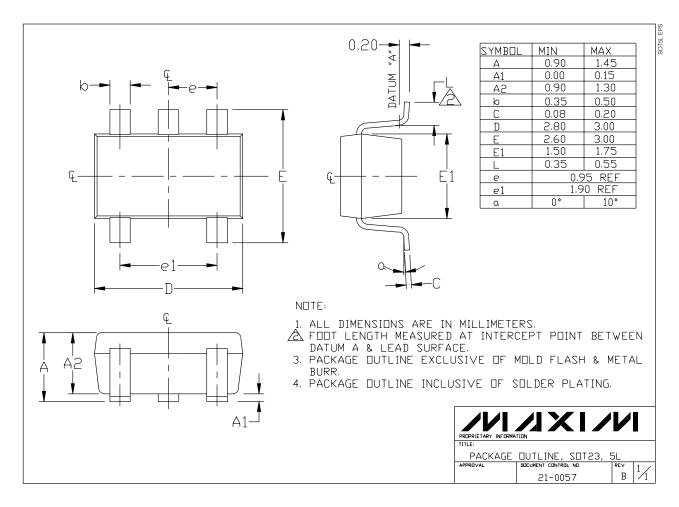
#### Pin Configurations/Functional Diagrams/Truth Tables (continued)

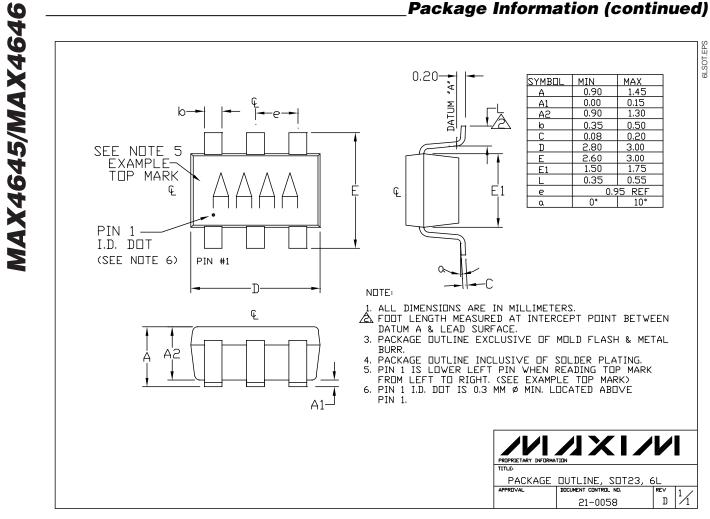
#### **Chip Information**

TRANSISTOR COUNT: 50

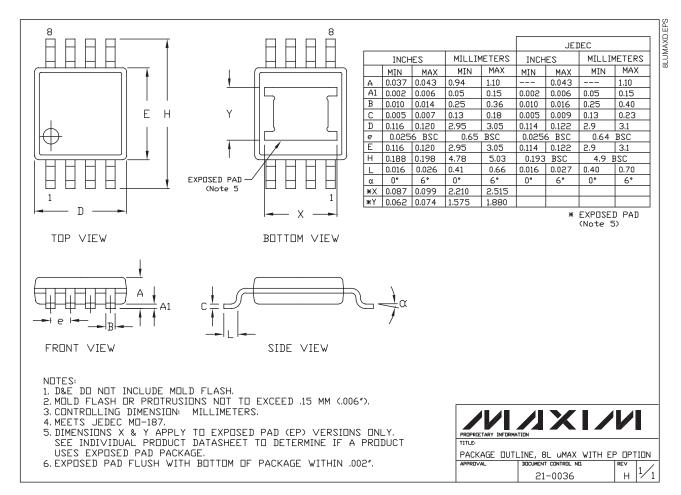
Figure 4. Off-Isolation/On-Channel Bandwidth

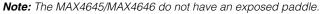
#### **Package Information**





#### Package Information (continued)





NOTES

Maxim cannot assume responsibility for use of any circuitry other than circuitry entirely embodied in a Maxim product. No circuit patent licenses are implied. Maxim reserves the right to change the circuitry and specifications without notice at any time.

12

\_\_\_\_\_Maxim Integrated Products, 120 San Gabriel Drive, Sunnyvale, CA 94086 (408) 737-7600

© 2000 Maxim Integrated Products

Printed USA

is a registered trademark of Maxim Integrated Products.